

Valley caloritronics by graphene nanoribbons

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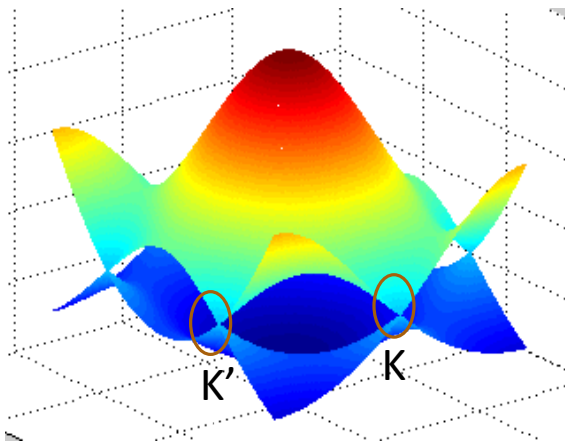
OUTLINE

- Introduction
- General physics of valley caloritronics
- Methods
- Results
- Conclusion

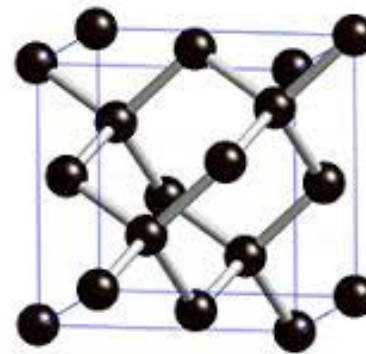
Valley

Another degree of freedom besides spin

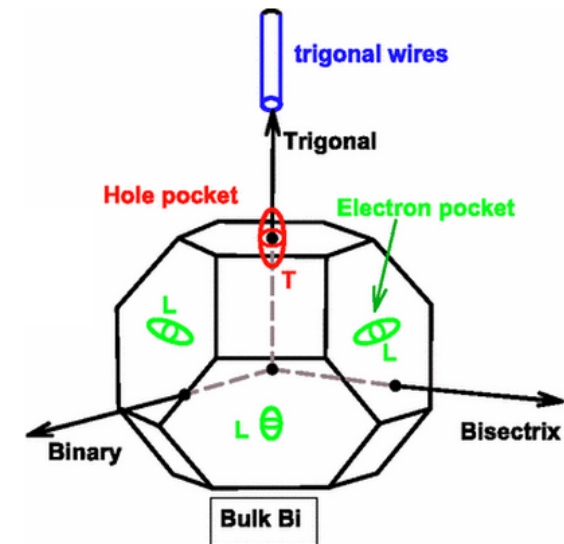
Graphene



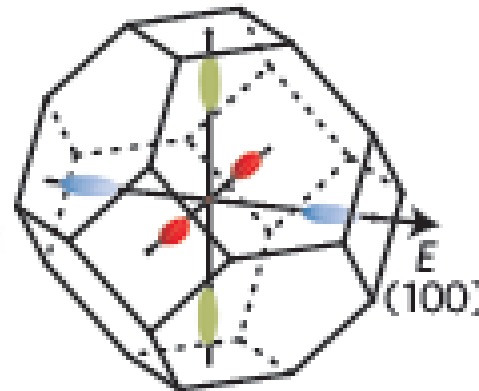
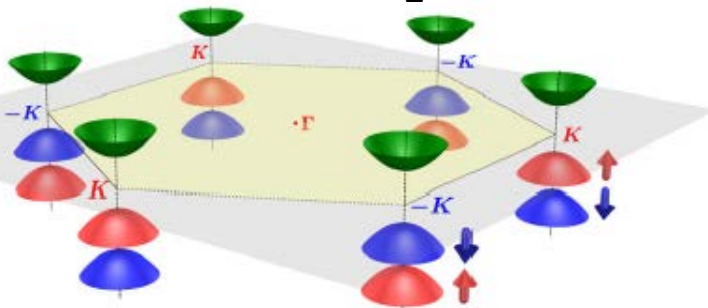
Diamond/Si



Bismuth



TMDCs-- MoS_2



Valleytronics

Challenge: achieving valley polarization

Analogous to spintronics

- *Encode information*
- *Make possible devices, such as valley filter and valve, and optoelectronic Hall devices*
-- J Feng et al. 2012
- *Robust against smooth deformation and low energy phonons because of the large valley separation in momentum space.*
-- D Xiao et al. 2012

Realization (expt.)

- Strain

- SiO₂/Si(100)/SiO₂ Quantum Well, 4 K, *K. Takashina, PRL(2006)*
- AlAs 2D electron gas, 0.3 K, *O. Gunawan, PRL(2006)*

- m^* anisotropy

- Magnetic field, Bismuth, 40 K, *K. Behnia, Nat. Phys(2012) 80% σ*
- High Electric field, Diamond, 77K, *J. Isberg Nat. Mater(2013) 98%*

- Optical excitation

- Monolayer MoS₂,
 - J. Feng, Nat. Commun. (2012) 50%, 300 K*
 - D. Xiao, Nat. Nanotech. (2012) 30%, up to 90 K*
 - Mak, Nat. Nanotech. (2012) valley Hall effect*

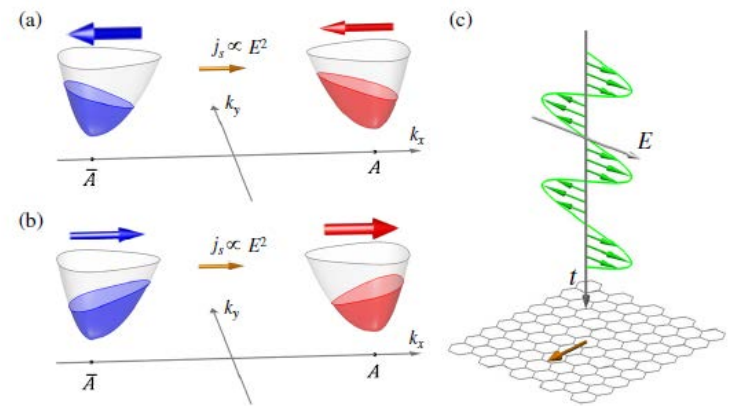
Realization

Thermally generate valley current ?

- Crystal anisotropy
 - Graphene and TMDCs,
W. Yao, Nat. Commun(2014)

- Valley filters

- Graphene nanojunctions, *Beenakker, Nat. Phys (2007)*
- CNT junctions, *H Santos, PRL(2009)*
- Graphene with grain boundaries, *CT White, PRL (2011)*



Thermal realization?

Valley Caloritronics

- Yes!
 - Crystal anisotropy *MoS₂, Yao et al., Nat. Commun.(2014)*
 - Thermoelectricity *Silicene, Niu et al., APL(2014)*
- ?
 - Can we have thermal valley filter?
 - Can we have 100% valley-polarized current?
 - Can we have pure thermal valley current?
- Another control method

Yes!

General physics

- Valley-resolved transmission: $\Xi^{1,2}(E)$

- Valley-resolved current

$$J_\eta = \frac{-2e}{h} \int (f_L - f_R) \cdot \Xi^\eta(E) dE, \quad (\eta = 1, 2)$$

Electrically or thermally

$J_1=0, J_2 \neq 0 \rightarrow$ 100% valley-polarized current

- Charge current $J_c = J_1 + J_2,$

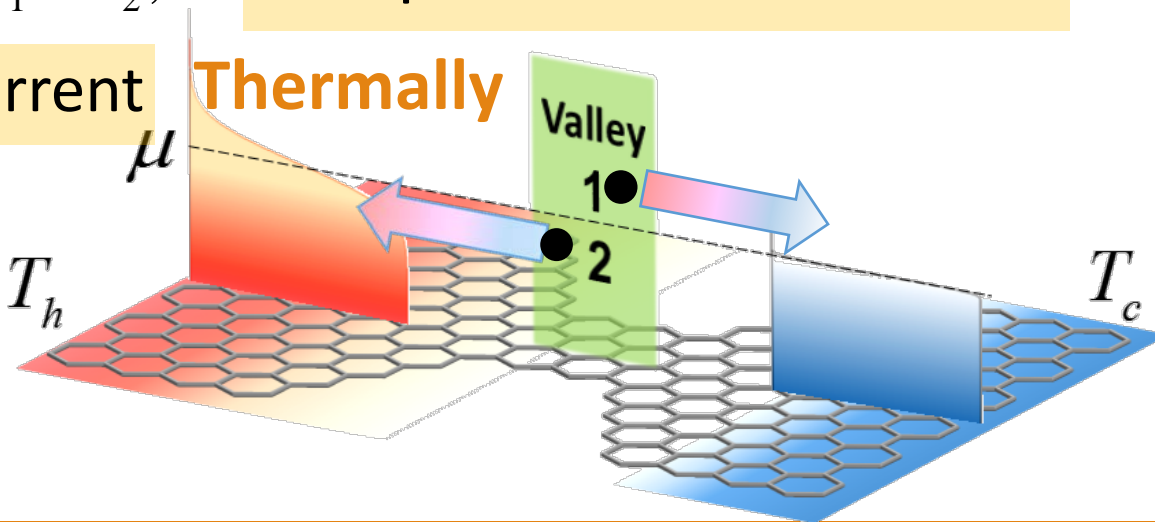
- Valley current $J_v = J_1 - J_2,$

$J_1 + J_2 = 0 \rightarrow$ Pure valley current

- Linear response

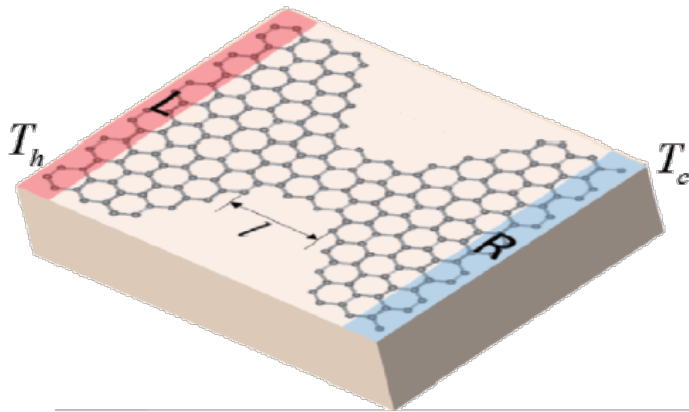
$$J_\eta = \underline{G_\eta} \Delta V + \underline{G_\eta S_\eta} \Delta T, \quad T_h$$

>0 >=< 0



Method

12/4/12 wedge-shaped GNR
 \approx 12-ZGNR/4-ZGNR/12-ZGNR



- ✓ Valley filters
- ✓ Simple
- ✓ Thermal stability
- ✓ Easily integrated to carbon circuits

- Nearest-neighbor tight-binding

$$H = \gamma \sum_{\langle i,j \rangle} c_i^+ c_j + \sum_i U_i c_i^+ c_i, \quad \gamma = -2.6 \text{ eV}$$

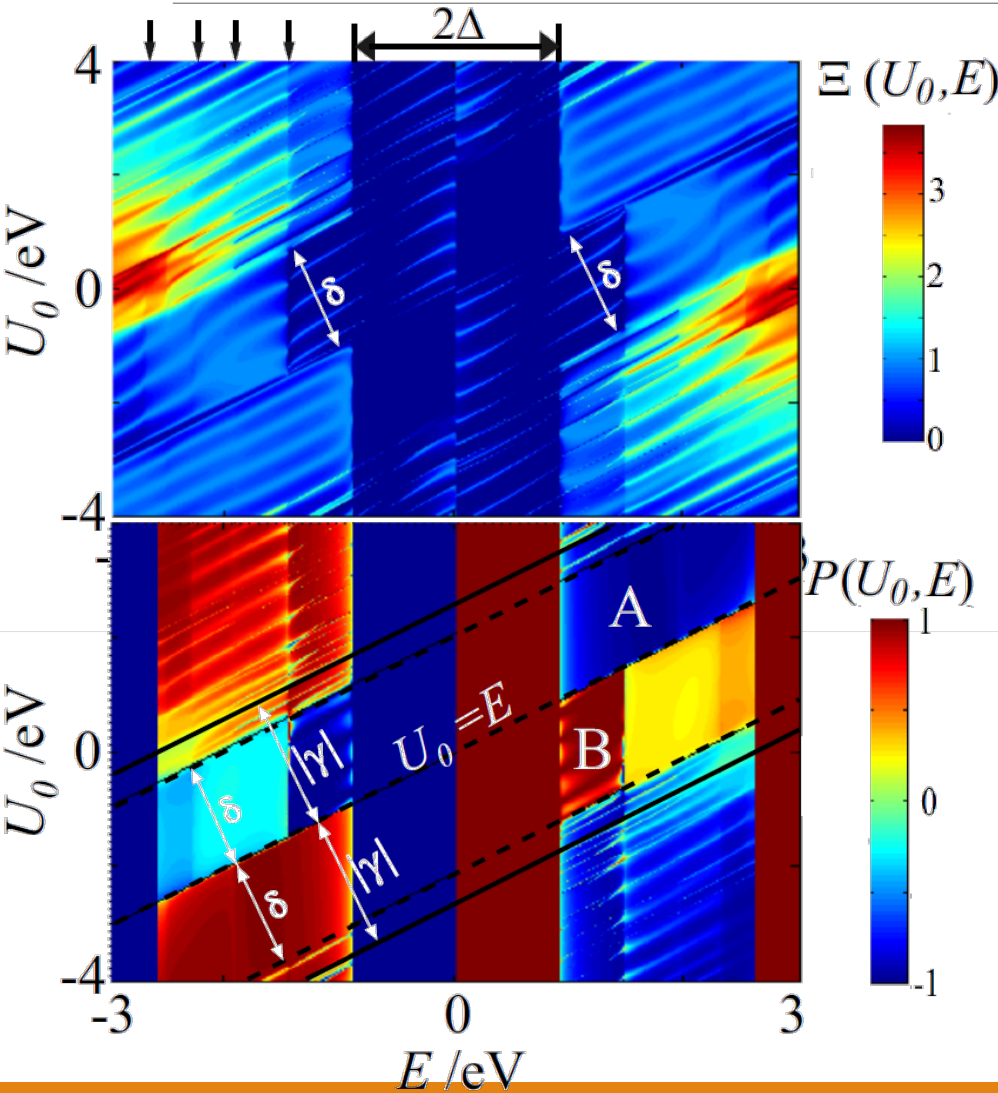
- $\Xi^{1,2}(E)$ Wave-matching method
S. Savito PRB(1999)

P.J. Kelly PRB(2005)

- Landauer formulism

$$J_\eta = \frac{-2e}{h} \int (f_L - f_R) \cdot \Xi^\eta(E) dE, \quad (\eta = 1, 2)$$

Transmission and Polarization

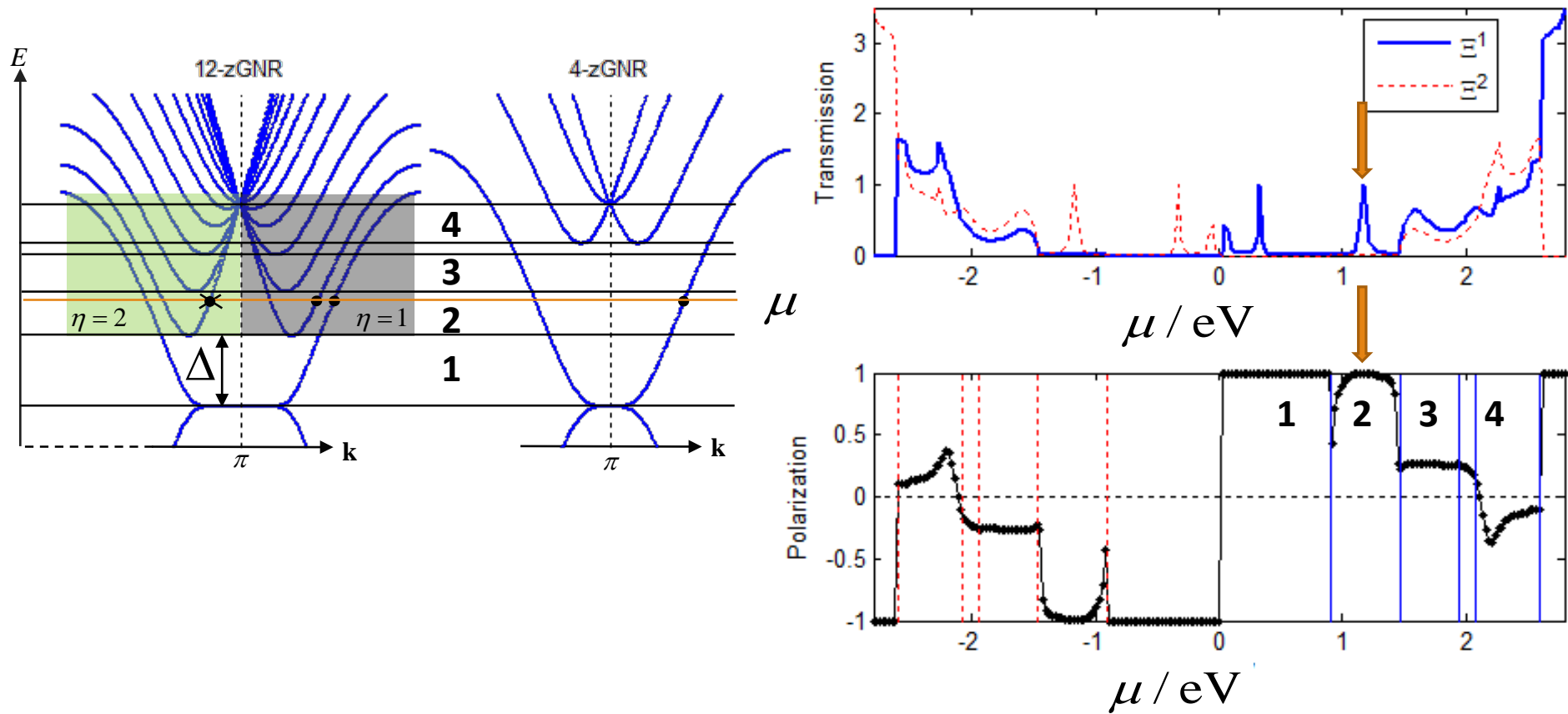


- Spiky structure
- Resonant tunneling
- e-h symmetry
- Band structure

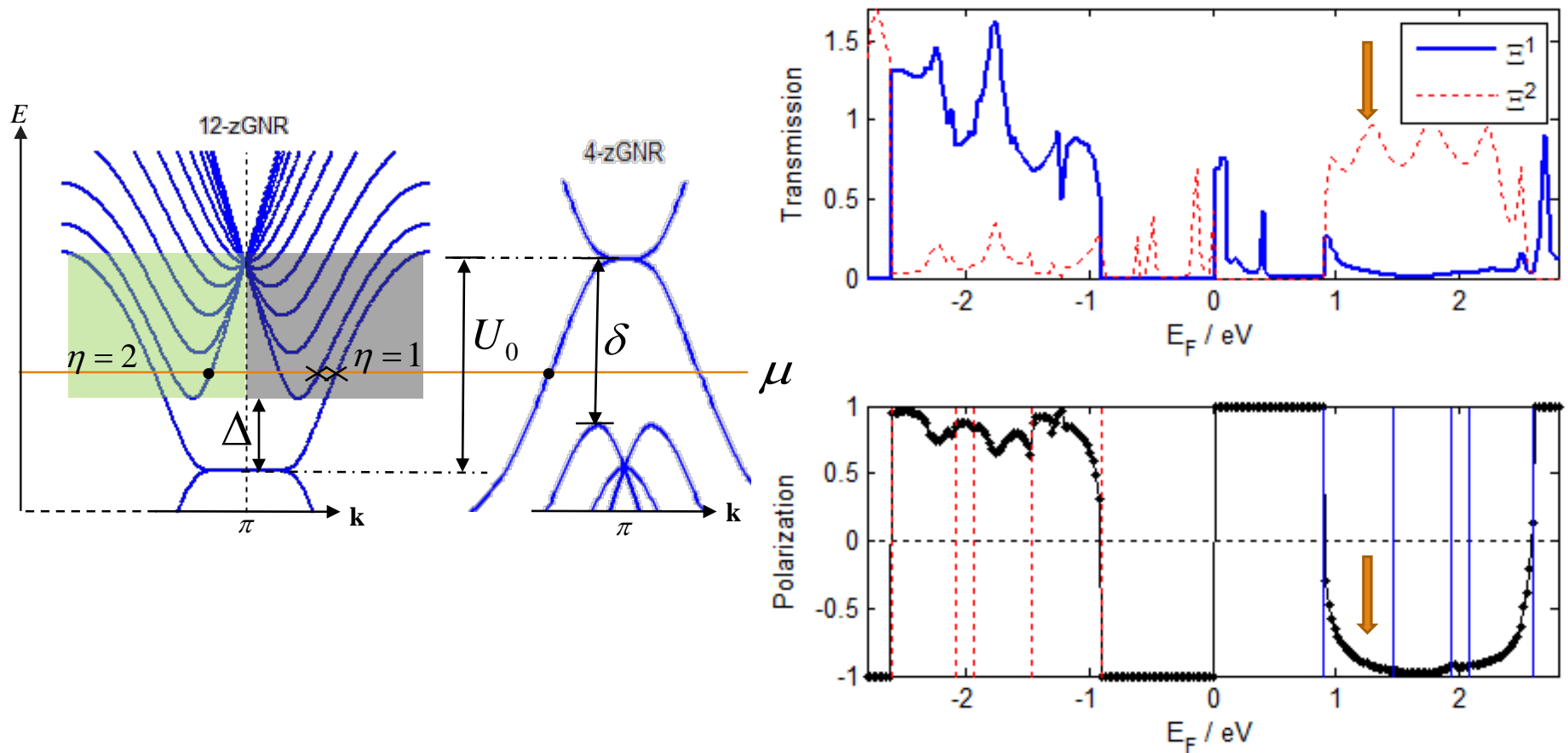
$$P(E) = \frac{\Xi^1(E) - \Xi^2(E)}{\Xi^1(E) + \Xi^2(E)}$$

- Excellent Valley filtering
- Related to transmission

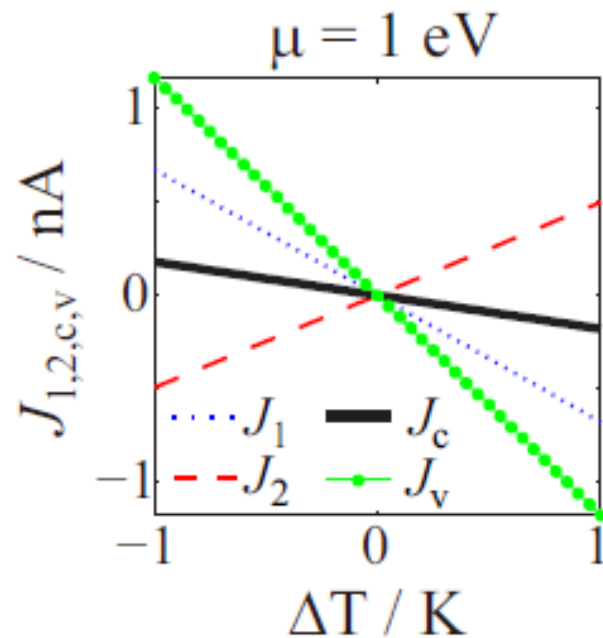
$$U_0 = 0 \text{ (B region)}$$



$U_0=2.6$ eV (A region)

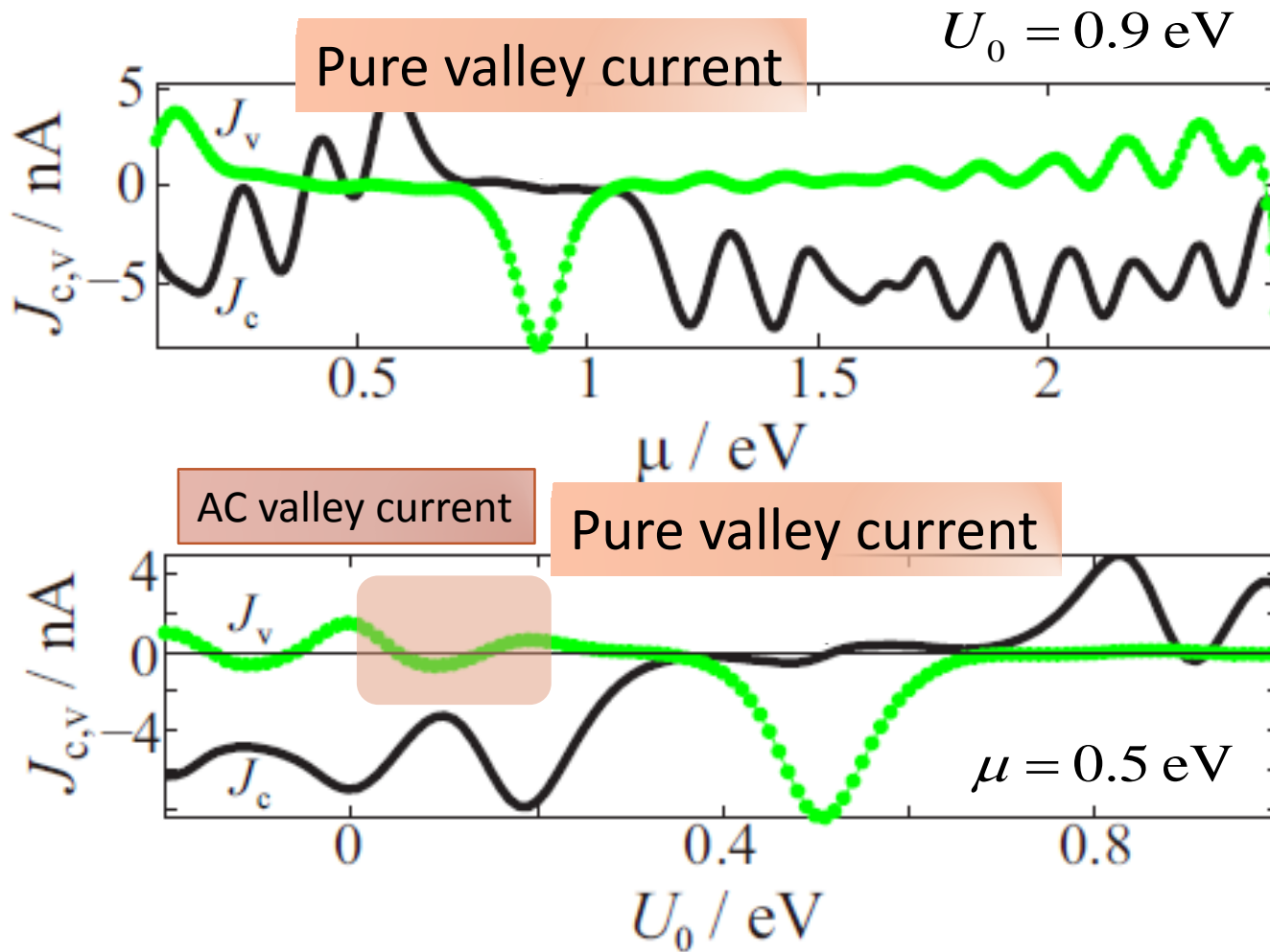


Thermal valley current



- $\square \Delta T$
- J_1, J_2 in different directions
- nA: Strong output due to first-order response
- Variational J_v : Depends on chemical potential

μ and gate control



Conclusion

- A general picture for valley caloritronics
- **Thermally driven** nearly **100% valley-polarized** and **pure valley current** can be obtained, with linearity maintained to large temperature difference.
- AC valley current can be obtained by varying the gate voltage without changing its polarity.

Acknowledgement

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○ Dr. Lei Zhang



Thank you!